

Silicon Fast Recovery Diode

$V_{RRM} = 50\text{ V} - 600\text{ V}$

$I_F = 20\text{ A}$

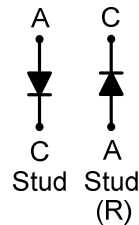
Features

- High Surge Capability
- Types up to 600 V V_{RRM}

DO-5 Package

Note:

1. Standard polarity: Stud is cathode.
2. Reverse polarity (R): Stud is anode.
3. Stud is base.



Maximum ratings, at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified ("R" devices have leads reversed)

| Parameter | Symbol | Conditions | FR20A(R)02 | FR20B(R)02 | FR20D(R)02 | FR20G(R)02 | FR20J(R)02 | Unit |
|--|------------|--|------------|------------|------------|------------|------------|------------------|
| Repetitive peak reverse voltage | V_{RRM} | | 50 | 100 | 200 | 400 | 600 | V |
| RMS reverse voltage | V_{RMS} | | 35 | 70 | 140 | 280 | 420 | V |
| DC blocking voltage | V_{DC} | | 50 | 100 | 200 | 400 | 600 | V |
| Continuous forward current | I_F | $T_C \leq 100\text{ }^\circ\text{C}$ | 20 | 20 | 20 | 20 | 20 | A |
| Surge non-repetitive forward current, Half Sine Wave | $I_{F,SM}$ | $T_C = 25\text{ }^\circ\text{C}$, $t_p = 8.3\text{ ms}$ | 250 | 250 | 250 | 250 | 250 | A |
| Operating temperature | T_j | | -40 to 125 | -40 to 125 | -40 to 125 | -40 to 125 | -40 to 125 | $^\circ\text{C}$ |
| Storage temperature | T_{stg} | | -40 to 150 | -40 to 150 | -40 to 150 | -40 to 150 | -40 to 150 | $^\circ\text{C}$ |

Electrical characteristics, at $T_j = 25\text{ }^\circ\text{C}$, unless otherwise specified

| Parameter | Symbol | Conditions | FR20A(R)02 | FR20B(R)02 | FR20D(R)02 | FR20G(R)02 | FR20J(R)02 | Unit |
|-----------------------|--------|---|------------|------------|------------|------------|------------|---------------|
| Diode forward voltage | V_F | $I_F = 20\text{ A}$, $T_j = 25\text{ }^\circ\text{C}$ | 1.4 | 1.4 | 1.4 | 1.4 | 1.4 | V |
| Reverse current | I_R | $V_R = 50\text{ V}$, $T_j = 25\text{ }^\circ\text{C}$ | 25 | 25 | 25 | 25 | 25 | μA |
| | | $V_R = 50\text{ V}$, $T_j = 150\text{ }^\circ\text{C}$ | 10 | 10 | 10 | 10 | 10 | mA |

Recovery Time

| | | | | | | | | |
|-------------------------------|----------|---|-----|-----|-----|-----|-----|----|
| Maximum reverse recovery time | T_{RR} | $I_F = 0.5\text{ A}$, $I_R = 1.0\text{ A}$, $I_{RR} = 0.25\text{ A}$ | 200 | 200 | 200 | 200 | 250 | nS |
|-------------------------------|----------|---|-----|-----|-----|-----|-----|----|

Thermal characteristics

| | | | | | | | | |
|-------------------------------------|------------|--|-----|-----|-----|-----|-----|--------------------|
| Thermal resistance, junction - case | R_{thJC} | | 0.6 | 0.6 | 0.6 | 0.6 | 0.6 | $^\circ\text{C/W}$ |
|-------------------------------------|------------|--|-----|-----|-----|-----|-----|--------------------|

Figure .1-Typical Forward Characteristics

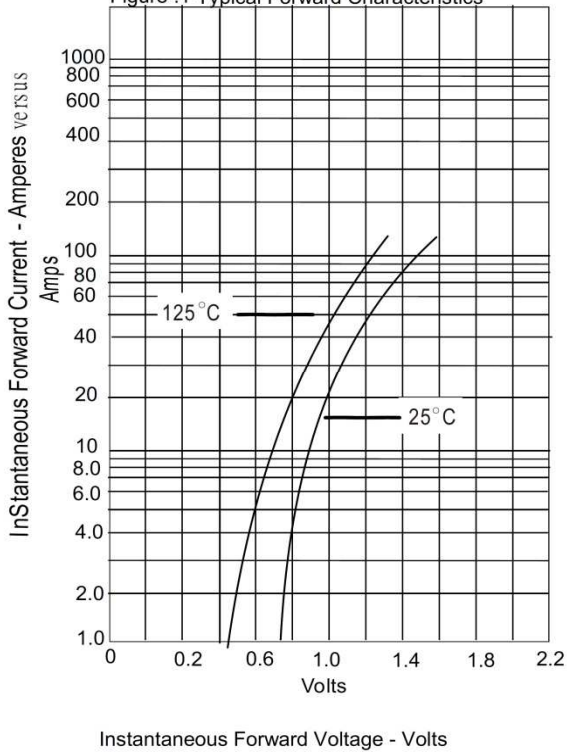


Figure .2- Forward Derating Curve

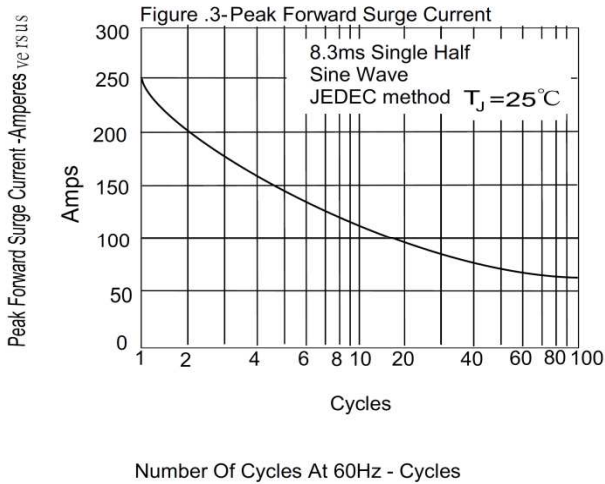
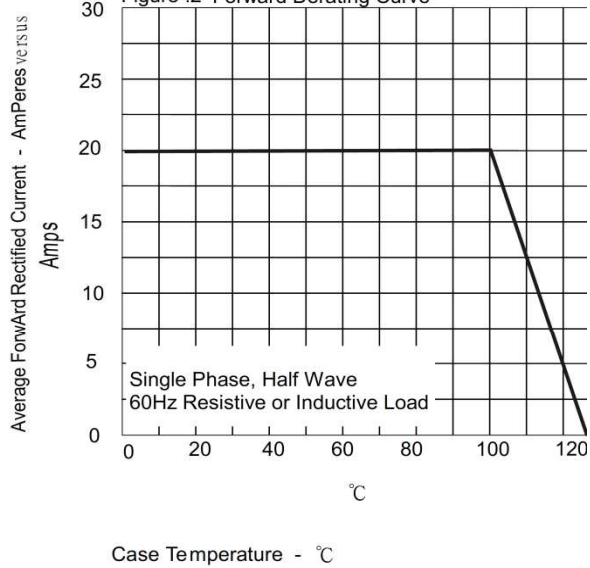


Figure .4 Typical Reverse Characteristics

